

December 2013

FQP8N90C / FQPF8N90C

N-Channel QFET® MOSFET

900 V, 6.3 A, 1.9 Ω

Description

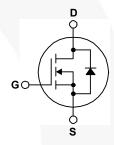
This N-Channel enhancement mode power MOSFET is • 6.3 A, 900 V, $R_{DS(on)}$ = 1.9 Ω (Max.) @ V_{GS} = 10 V, produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state • Low Gate Charge (Typ. 35 nC) resistance, and to provide superior switching performance • Low Crss (Typ. 12 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power • 100% Avalanche Tested factor correction (PFC), and electronic lamp ballasts.

Features

- $I_D = 3.15 A$







Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FQP8N90C	FQPF8N90C	Unit
V_{DSS}	Drain-Source Voltage		900		V
I _D	Drain Current - Continuous (T _C = 25°C)		6.3	6.3 *	Α
	- Continuous (T _C = 100°C)		3.8	3.8 *	Α
I _{DM}	Drain Current - Pulsed	(Note 1)	25	25 *	Α
V _{GSS}	Gate-Source Voltage		± 30		V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	850		mJ
I _{AR}	Avalanche Current	(Note 1)	6.3		Α
E _{AR}	Repetitive Avalanche Energy (Not		17.1		mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3		4.0		V/ns
P_D	Power Dissipation (T _C = 25°C)		171	60	W
	- Derate above 25°C	1.37	0.48	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150		°C
T _L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300		°C

^{*} Drain current limited by maximum junction temperature.

Thermal Characteristics

Symbol	Parameter	FQP8N90C	FQP89N90C	Unit
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.73	2.08	°C/W
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink Typ, Max.	0.5		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	62.5	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FQP8N90C	FQP8N90C	TO-220	Tube	N/A	N/A	50 units
FQPF8N90C	FQPF8N90C	TO-220F	Tube	N/A	N/A	50 units

Flectrical Characteristics

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Cha	aracteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	900			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μ A, Referenced to 25°C		0.95		V/°C
I _{DSS} Zero (7 0 1 1/1 1 2 1 0 1	V _{DS} = 900 V, V _{GS} = 0 V			10	μА
	Zero Gate Voltage Drain Current	V _{DS} = 720 V, T _C = 125°C		-	100	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 30 V, V _{DS} = 0 V			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -30 V, V _{DS} = 0 V		1	-100	nA
On Cha	aracteristics					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10 V, I _D = 3.15 A		1.6	1.9	Ω
9 _{FS}	Forward Transconductance	V _{DS} = 50 V, I _D = 3.15 A		5.5		S
Dynam	ic Characteristics					
C _{iss}	Input Capacitance	V _{DS} = 25 V, V _{GS} = 0 V,		1600	2080	pF
C _{oss}	Output Capacitance	f = 1.0 MHz		130	170	pF
C _{rss}	Reverse Transfer Capacitance			12	15	pF
Switchi	ing Characteristics					
t _{d(on)}	Turn-On Delay Time			40	90	ns
t _r	Turn-On Rise Time	$V_{DD} = 450 \text{ V}, I_D = 8 \text{ A},$ $R_G = 25 \Omega$		110	230	ns
t _{d(off)}	Turn-Off Delay Time	NG - 23 32		70	150	ns
t _f	Turn-Off Fall Time	(Note 4)		70	150	ns
Qg	Total Gate Charge	V _{DS} = 720 V, I _D = 8 A,		35	45	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10 V	/	10		nC
Q _{gd}	Gate-Drain Charge	(Note 4)		14		nC
	Source Diode Characteristics a	nd Maximum Ratings				
I _S	Maximum Continuous Drain-Source Diode Forward Current				6.3	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current			-	25	Α
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_S = 6.3 \text{ A}$)	1.4	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _S = 8 A,		530	//	ns
Q _{rr}	Reverse Recovery Charge	dI _F / dt = 100 A/μs		5.8		μС

- Notes: 1. Repetitive rating: pulse-width limited by maximum junction temperature. 2. L = 40 mH, I_{AS} = 6.3 A, V_{DD} = 50 V, R_{G} = 25 Ω , starting T_{J} = 25°C. 3. I_{SD} ≤ 8 A, di/dt ≤ 200 A/ μ s, V_{DD} ≤ BV $_{DSS}$, starting T_{J} = 25°C. 4. Essentially independent of operating temperature.

Typical Characteristics

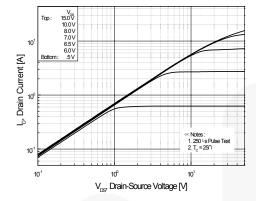


Figure 1. On-Region Characteristics

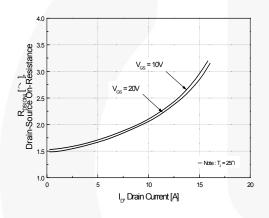


Figure 3. On-Resistance Variation vs Drain Current and Gate Voltage

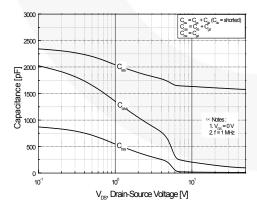


Figure 5. Capacitance Characteristics

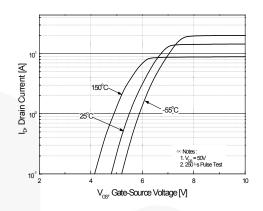


Figure 2. Transfer Characteristics

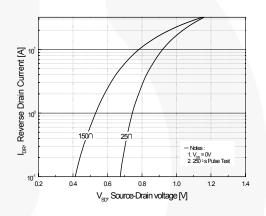


Figure 4. Body Diode Forward Voltage Variation with Source Current and Temperature

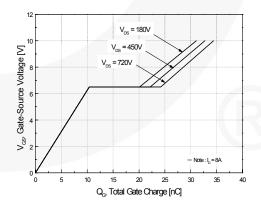


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

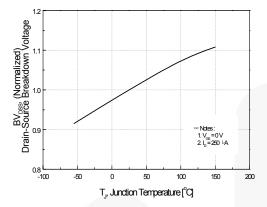


Figure 7. Breakdown Voltage Variation vs Temperature

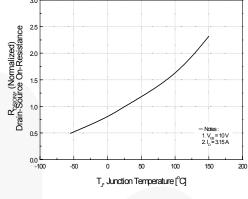


Figure 8. On-Resistance Variation vs Temperature

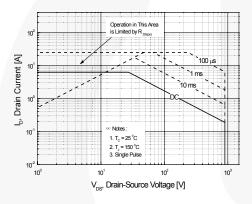


Figure 9-1. Maximum Safe Operating Area for FQP8N90C

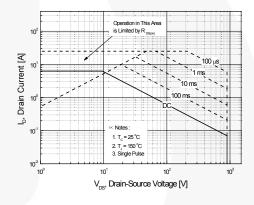


Figure 9-2. Maximum Safe Operating Area for FQPF8N90C

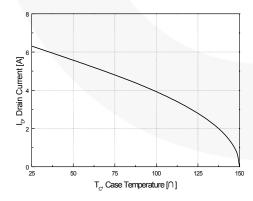


Figure 10. Maximum Drain Current vs Case Temperature

Typical Characteristics (Continued)

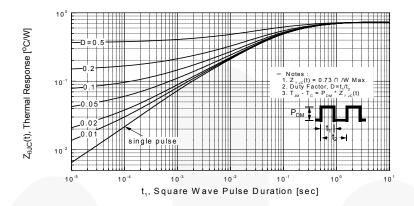


Figure 11-1. Transient Thermal Response Curve for FQP8N90C

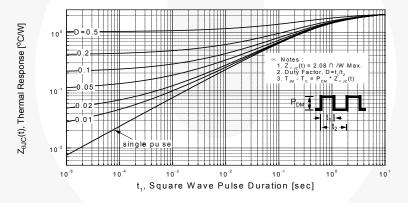


Figure 11-2. Transient Thermal Response Curve for FQPF8N90C

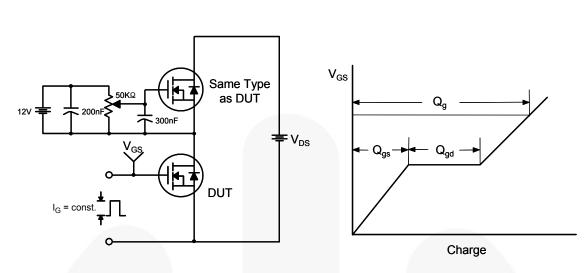


Figure 12. Gate Charge Test Circuit & Waveform

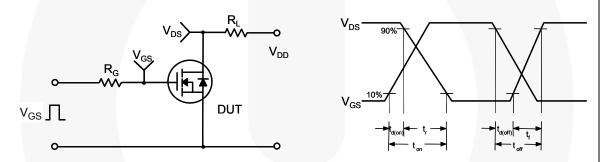


Figure 13. Resistive Switching Test Circuit & Waveforms

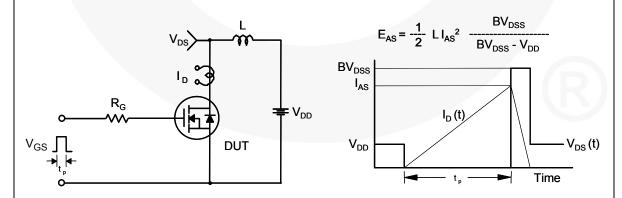
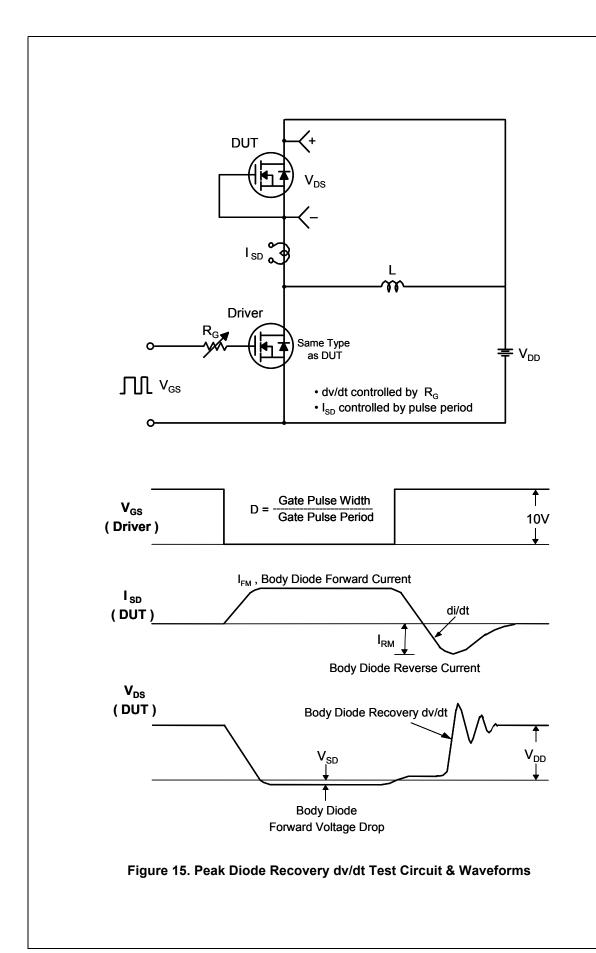


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms



Mechanical Dimensions

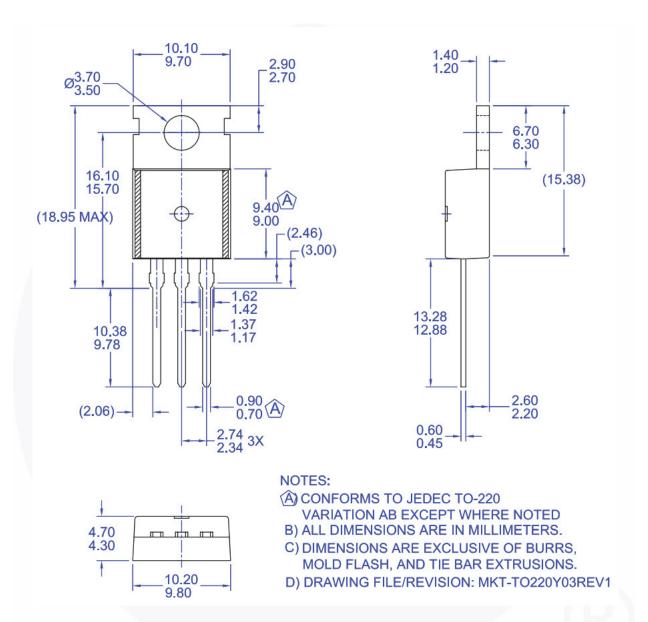


Figure 16. TO220, Molded, 3-Lead, Jedec Variation AB

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Mechanical Dimensions

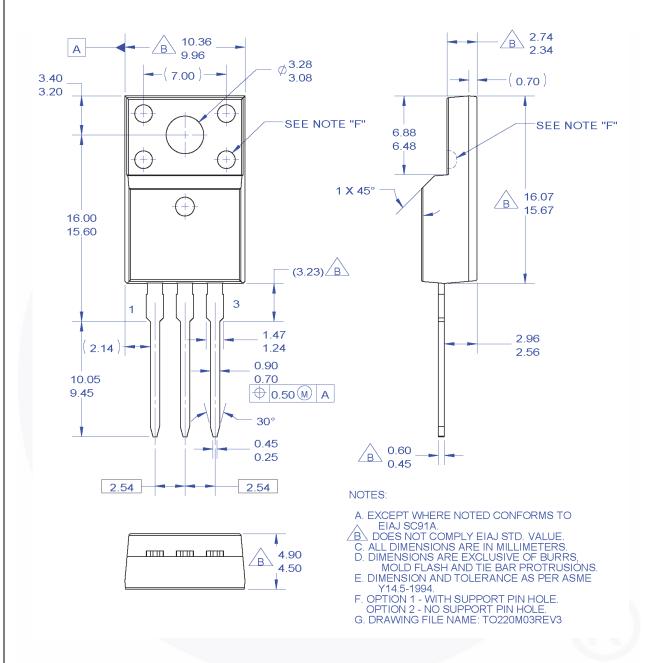


Figure 17. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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9

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